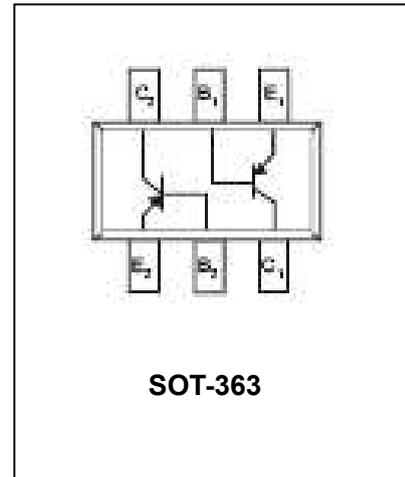


Dual PNP Small Signal Surface Mount Transistor **MMDT2907A**

FEATURES

- Epitaxial planar die construction.
- Complementary NPN type available MMDT2222A.
- Ultra-small surface mount package.



APPLICATIONS

- For Low power amplification and switching.

ORDERING INFORMATION

Type No.	Marking	Package Code
MMDT2907A	K2F	SOT-363

MAXIMUM RATING @ Ta=25°C unless otherwise specified

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	-60	V
V_{CEO}	Collector-Emitter Voltage	-60	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_C	Collector Current -Continuous	-600	mA
P_D	Power Dissipation	200	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	625	°C/W
T_j, T_{stg}	Junction and Storage Temperature	-55 to +150	°C

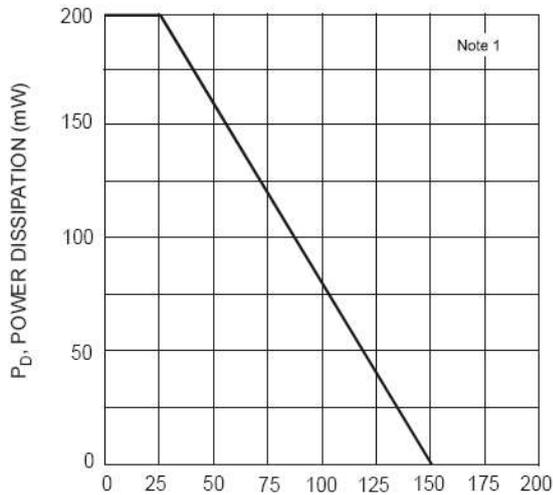
Dual PNP Small Signal Surface Mount Transistor MMDT2907A

ELECTRICAL CHARACTERISTICS @ Ta=25°C unless otherwise specified

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=-10\mu A$ $I_E=0$	-60	-	V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=-10mA$ $I_B=0$	-60	-	V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=-10\mu A$ $I_C=0$	-5	-	V
Collector cut-off current	I_{CBO}	$V_{CB}=-50V$ $I_E=0$ $V_{CB}=-50V$ $I_E=0$ $T_A=125^\circ C$	-	-10	nA μA
Collector cut-off current	I_{CEX}	$V_{CE}=-30V$, $V_{EB(OFF)}=-0.5V$	-	-50	nA
Base cut-off current	I_{BL}	$V_{CE}=-30V$, $V_{EB(OFF)}=-0.5V$	-	-50	nA
DC current gain	h_{FE}	$V_{CE}=-10V$ $I_C=-100\mu A$	75	-	-
		$V_{CE}=-10V$ $I_C=-1.0mA$	100	-	
		$V_{CE}=-10V$ $I_C=-10mA$	100	-	
		$V_{CE}=-10V$ $I_C=-150mA$	100	300	
		$V_{CE}=-10V$ $I_C=-500mA$	50	-	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=-150mA$ $I_B=-15mA$ $I_C=-500mA$ $I_B=-50mA$	-	-0.4 -1.6	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=-150mA$ $I_B=-15mA$ $I_C=-500mA$ $I_B=-50mA$	-	-1.3 -2.6	V
Transition frequency	f_T	$V_{CE}=-20V$ $I_C=-50mA$ $f=100MHz$	200	-	MHz
Output Capacitance	C_{obo}	$V_{CB}=-10V$, $f=1.0MHz$, $I_E=0$	-	8	pF
Input Capacitance	C_{ibo}	$V_{EB}=-2.0V$, $f=1.0MHz$, $I_C=0$	-	30	pF
Turn-On Time	t_{on}	$V_{CC}=-30V$, $I_C=-150mA$, $I_{B1}=-15mA$	-	45	ns
Delay time	t_d		-	10	ns
Rise time	t_r		-	40	ns
Turn-Off Time	T_{off}		-	100	ns
Storage time	t_s	$V_{CC}=-6V$, $I_C=-150mA$ $I_{B1}=-I_{B2}=-15mA$	-	225	ns
Fall time	t_f		-	60	ns

Dual PNP Small Signal Surface Mount Transistor **MMDT2907A**

TYPICAL CHARACTERISTICS @ $T_a=25^\circ\text{C}$ unless otherwise specified



T_A , AMBIENT TEMPERATURE ($^\circ\text{C}$)
 Fig. 1, Max Power Dissipation vs. Ambient Temperature (Total Device)

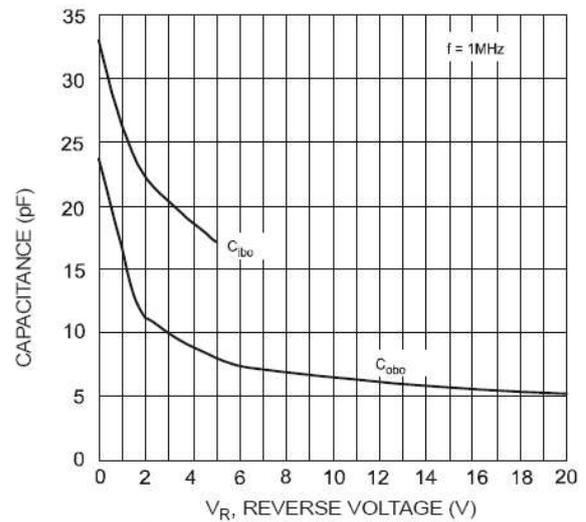


Fig. 2, Typical Capacitance Characteristics

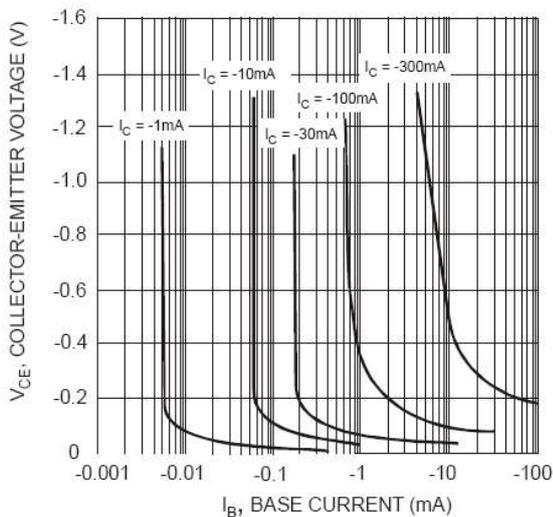


Fig. 3, Typical Collector Saturation Region

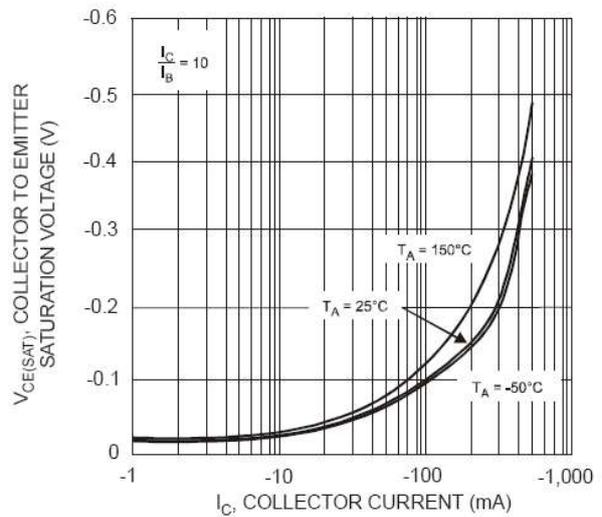


Fig. 4, Collector Emitter Saturation Voltage vs. Collector Current

Dual PNP Small Signal Surface Mount Transistor MMDT2907A

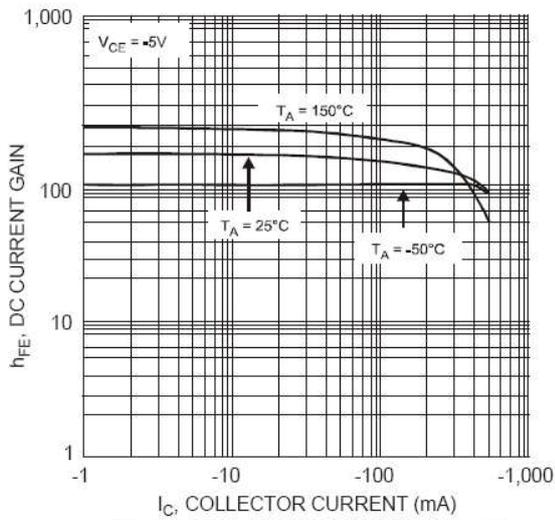


Fig. 5, DC Current Gain vs. Collector Current

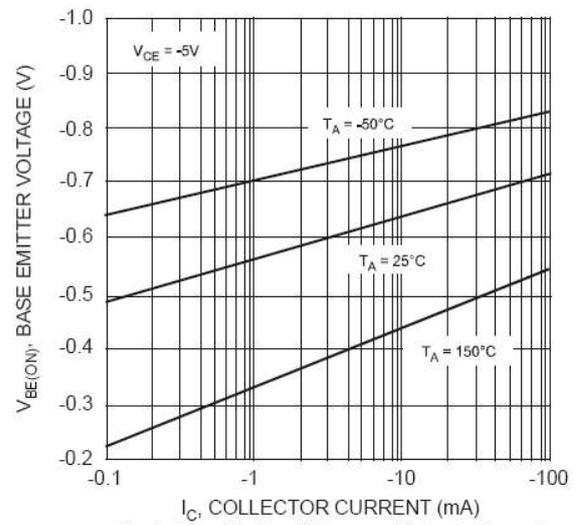


Fig. 6, Base Emitter Voltage vs. Collector Current

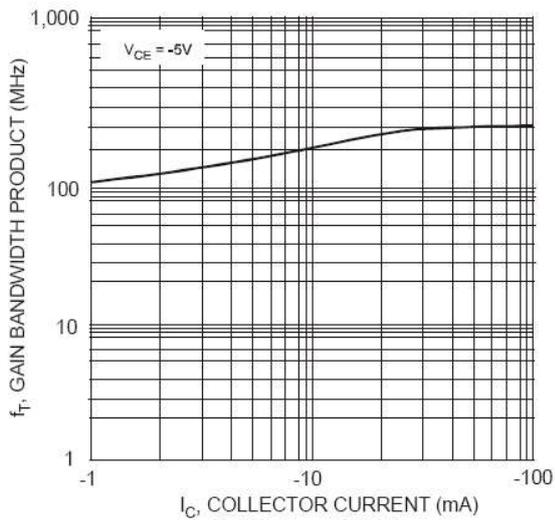


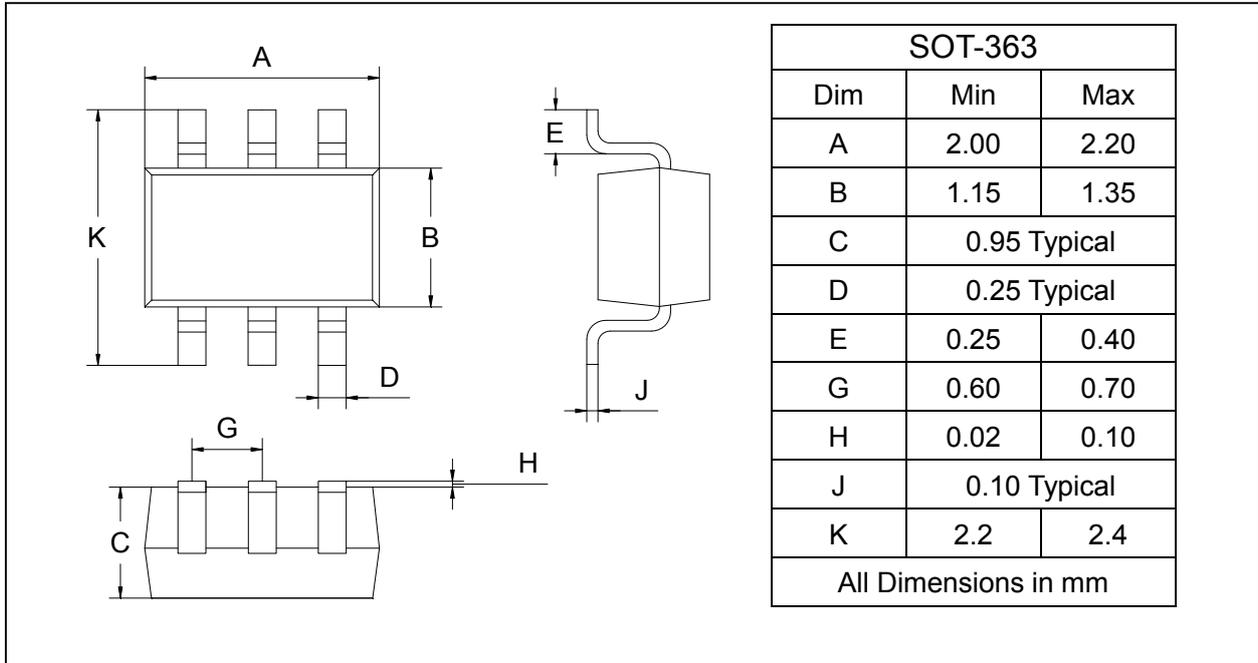
Fig. 7, Gain Bandwidth Product vs. Collector Current

Dual PNP Small Signal Surface Mount Transistor MMDT2907A

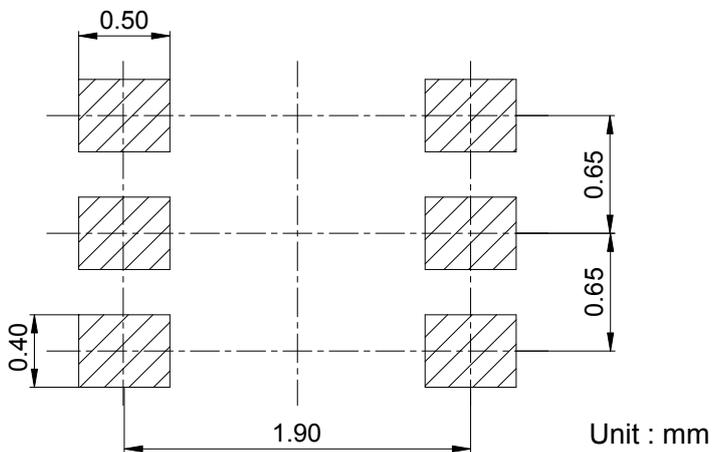
PACKAGE OUTLINE

Plastic surface mounted package

SOT-363



SOLDERING FOOTPRINT



PACKAGE INFORMATION

Device	Package	Shipping
MMDT2907A	SOT-363	3000/Tape&Reel